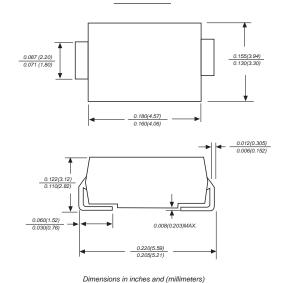


# **S2A THRU S2M**

### SURFACE MOUNT GENERAL RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 2.0 Amperes

#### DO-214AA



### **FEATURES**

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- Low reverse leakage
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds at terminals

#### **MECHANICAL DATA**

Case: JEDEC DO-214AA molded plastic body

Terminals: Solder plated, solderable per MIL-STD-750,

Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.005 ounce, 0.138 grams

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	S2A	S2B	S2D	S2G	S2J	S2K	S2M	UNITS
Maximum repetitive peak reverse voltage	Vrrm	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	VRMS	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	VDC	50 100 200 400 600 800 1000					VOLTS		
Maximum average forward rectified current at TL=110°C	l <sub>(AV)</sub>	2.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	lfsm	60.0							Amps
Maximum instantaneous forward voltage at 2.0A	VF	1.1							Volts
Maximum DC reverse current T <sub>A</sub> =25℃ at rated DC blocking voltage T <sub>A</sub> =100℃	lr	5.0 50.0						μА	
Typical junction capacitance (NOTE 1)	C¹	30.0							pF
Typical thermal resistance (NOTE 2)	RθJA	50.0						°C/W	
Operating junction and storage temperature range	ТЈ,Тѕтс	-50 to +150							°C

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C. 2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas



## **RATINGS AND CHARACTERISTIC CURVES S2A THRU S2M**

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE 2.0 1.2 Single Phase Half Wave 60Hz Resistive or inductive Load 0.8 0.4 0 25 50 75 100 125 150 175 AMBIENT TEMPERATURE.°C



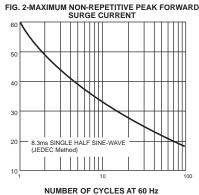
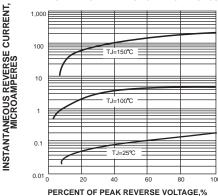
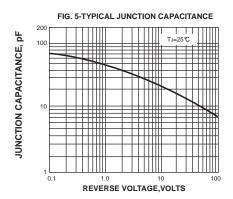


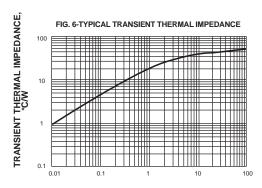
FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS INSTANTANEOUS FORWARD CURRENT, AMPERES 20 TJ=25 °C PULSE WIDTH=300 μs 1%DUTY CYCLE 0.01 1.0 1.2 1.4

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE.





t.PULSE DURATION.sec.

The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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